

N-Channel Enhancement Mode Field Effect Transistor

2N7002T

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- This Device is Pb-Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	60	V
Drain-Gate Voltage R _{GS} ≤ 1.0 MΩ	V _{DGR}	60	V
Gate-Source Voltage Continuous Pulsed	V _{GSS}	±20 ±40	V
Gate-Source Voltage Continuous Continuous at 100°C Pulsed	I _D	115 73 800	mA
Junction Temperature Range	T _J	150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

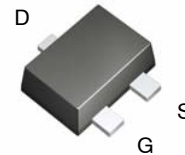
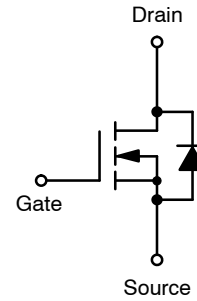
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Max	Unit
Total Device Dissipation Derating above T _A = 25°C	P _D	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	R _{θJA}	625	°C/W

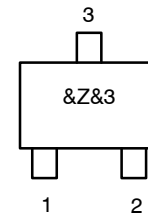
1. Device mounted on FR-4 PCB, 1 inch × 0.85 inch × 0.062 inch. Minimum land pad size.

SIMPLIFIED SCHEMATIC



SOT-523FL
CASE 419BG

MARKING DIAGRAM



&Z = Assembly location
&3 = Data code

ORDERING INFORMATION

Device	Package	Shipping†
2N7002T	SOT-523FL (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

2N7002T

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
OFF CHARACTERISTICS (Note 2)						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0\text{ V}, I_D = 10\ \mu\text{A}$	60	78	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 60\text{ V}, V_{GS} = 0\text{ V}$	-	0.001	1.0	μA
		$V_{GS} = 60\text{ V}, V_{DS} = 0\text{ V}$ $T_J = 125^\circ\text{C}$	-	7	500	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	-	0.2	± 10	nA

ON CHARACTERISTICS

 (Note 2)

Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	1.0	1.76	2.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 5\text{ V}, I_D = 0.05\text{ A}$	-	1.6	7.5	Ω
		$V_{GS} = 10\text{ V}, I_D = 0.5\text{ A}$	-	-	2.0	Ω
		$V_{GS} = 10\text{ V}, I_D = 0.5\text{ A},$ $T_J = 125^\circ\text{C}$	-	2.53	13.5	Ω
On-State Drain Current	$I_{D(on)}$	$V_{GS} = 10\text{ V}, V_{DS} = 7.5\text{ V}$	0.5	1.43	-	A
Forward Transconductance	g_{FS}	$V_{DS} = 10\text{ V}, I_D = 0.2\text{ A}$	80	356.5	-	mS

DYNAMIC CHARACTERISTICS

Input Capacitance	C_{ISS}	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$	-	37.8	50	pF
Output Capacitance	C_{OSS}		-	12.4	25	
Reverse Transfer Capacitance	C_{RSS}		-	6.5	7.0	

SWITCHING CHARACTERISTICS

Turn-On Delay Time	$t_{D(on)}$	$V_{DD} = 30\text{ V}, I_D = 0.2\text{ A},$ $V_{GEN} = 10\text{ V}, R_L = 150\ \Omega,$ $R_{GEN} = 25\ \Omega$	-	5.85	20	ns
Turn-Off Delay Time	$t_{D(off)}$		-	12.5	20	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Short duration test pulse used to minimize self-heating effect.

TYPICAL PERFORMANCE CHARACTERISTICS

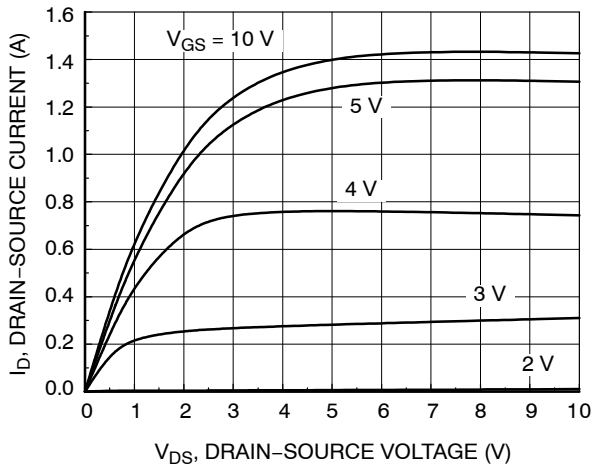


Figure 1. On-Region Characteristics

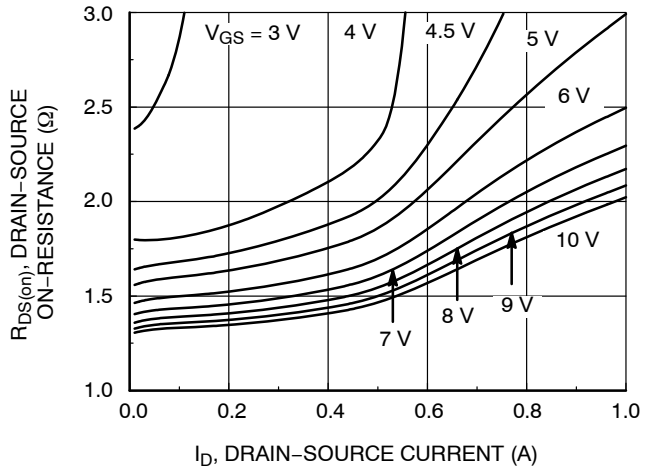


Figure 2. On-Resistance Variation with Gate Voltage and Drain Current

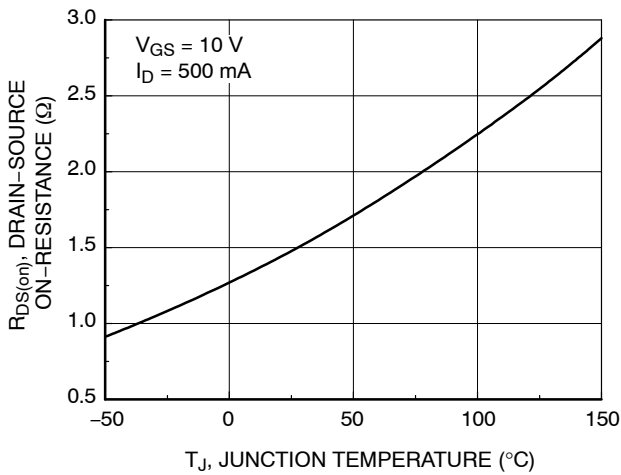


Figure 3. On-Resistance Variation with Temperature

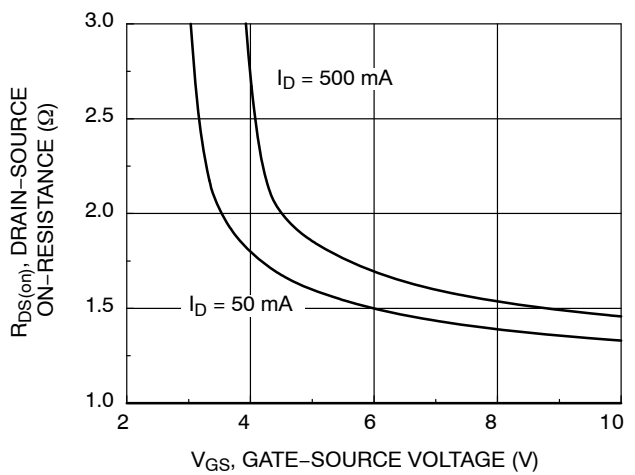


Figure 4. On-Resistance Variation with Gate-Source Voltage

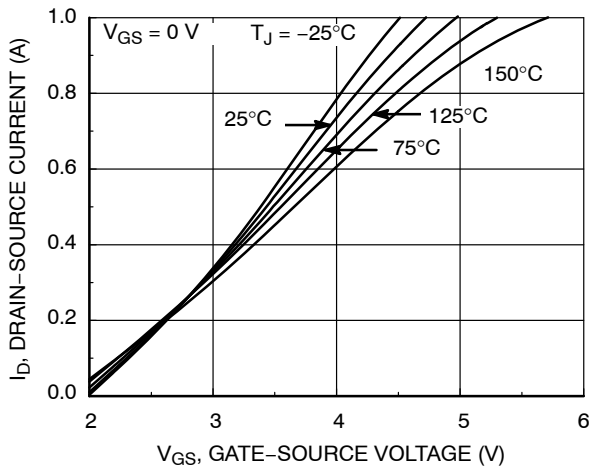


Figure 5. Transfer Characteristics

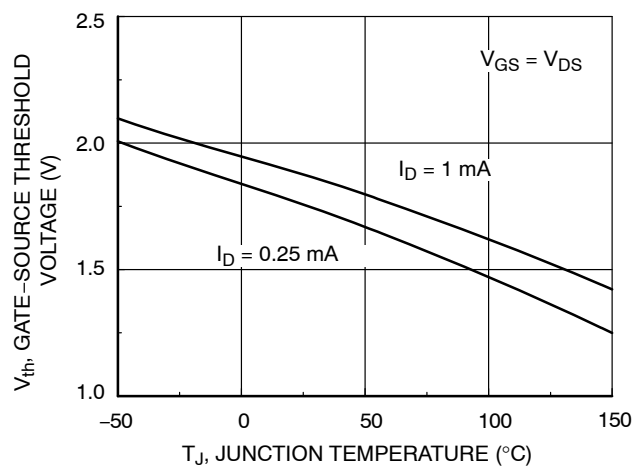


Figure 6. Gate Threshold Variation with Temperature

2N7002T

TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

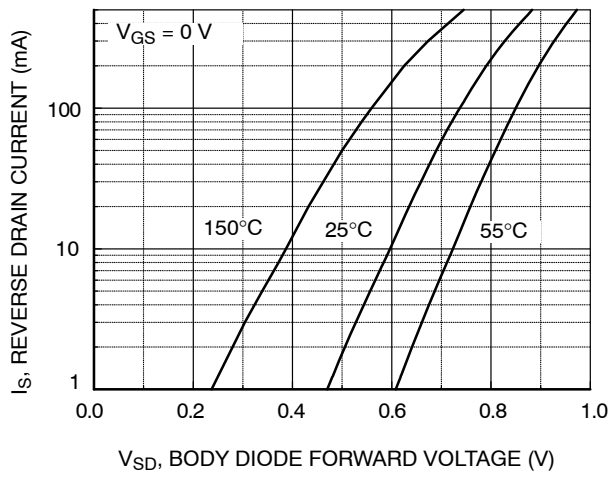


Figure 7. Reverse Drain Current Variation with Diode Forward Voltage and Temperature

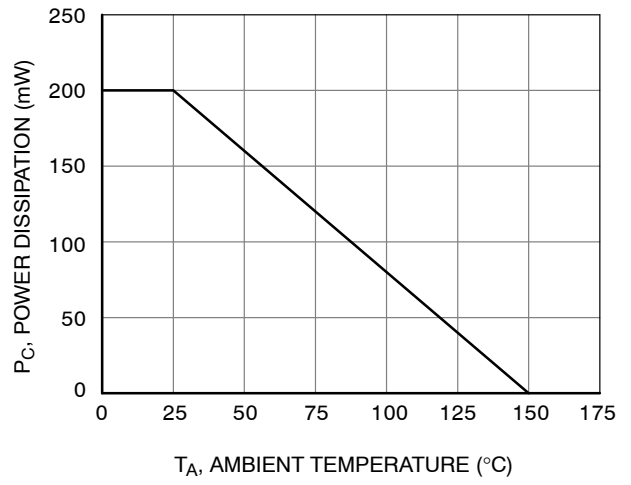
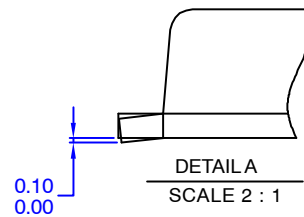
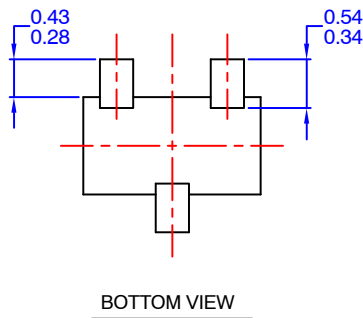
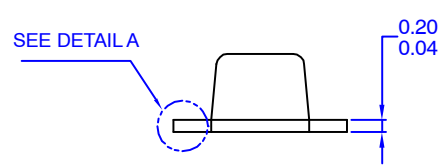
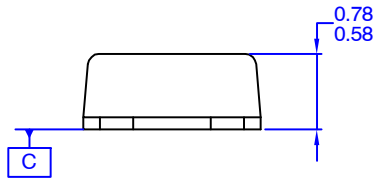
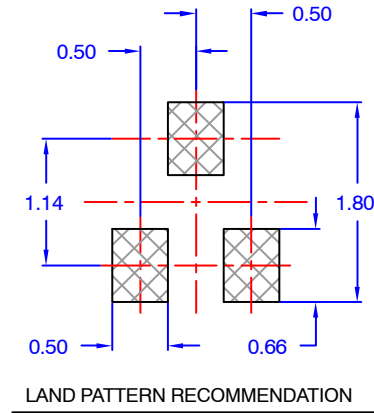
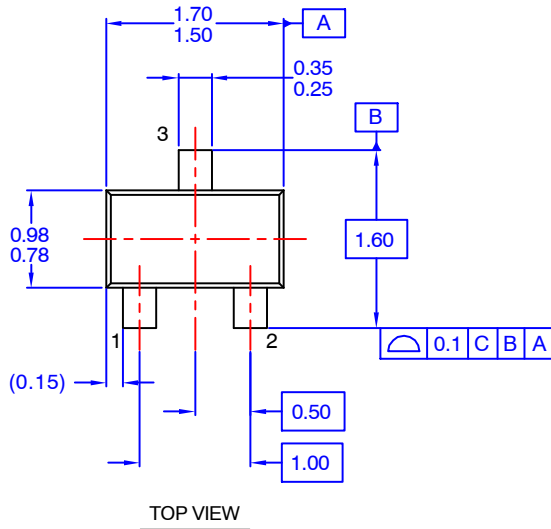


Figure 8. Power Derating



SOT-523FL
CASE 419BG
ISSUE A

DATE 29 SEP 2017



NOTES:

- A) THIS PACKAGE CONFORMS TO EIAJ SC89 PACKAGING STANDARD.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994
- D) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

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DESCRIPTION:	SOT-523FL	PAGE 1 OF 1

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